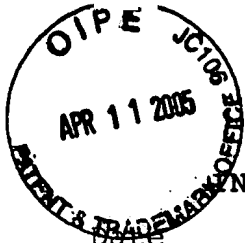


ONS00504  
JLW



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Date : 4/7/2005

IN RE APPLICATION OF: Stephen P. Robb

APPLN. NO. : 10/678769

FILED : 10/6/2003

FOR : POWER SWITCH STRUCTURE WITH LOW  
RDSON AND LOW CURRENT LIMIT AND METHOD

EXAMINER : Ngan Ngo

Phone : 571-272-1711

Group : 2832

**DISCLOSURE STATEMENT UNDER 37 C.F.R. 1.97**

Honorable Assistant Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

SIR:

Please consider this Information Disclosure Statement in the above application. Applicant's undersigned representative hereby certifies that each item of information contained in the attached Information Disclosure Statement was cited in a communication from a foreign patent office in a counterpart foreign application not more than three months prior to the filing of this statement. A copy of the listed prior art is enclosed herewith.

A copy of the International Search Report received in the counterpart application is also enclosed.

No representation is made or intended that a search has been made or that no better prior art than that listed is available.

Respectfully submitted,  
Stephen P. Robb, et al.

ON Semiconductor  
Intellectual Property Dept.  
P.O. Box 62890 - A700  
Phoenix, AZ 85062-2890  
Customer #: 2725

Kevin B. Jackson  
Reg. #38,502  
Phone: 602-244-4885  
Fax: 602-244 3169

FORM PTO-1449

U.S. DEPARTMENT OF  
COMMERCEPATENT AND TRADEMARK  
OFFICEATTY. DOCKET NO.  
ONS00504SERIAL NO.  
10/678769INFORMATION DISCLOSURE  
STATEMENT BY APPLICANT

(Use several sheets if necessary)

APPLICANT  
Stephen P. Robb et al.FILING DATE  
10/6/2003GROUP  
2832

## U.S. PATENT DOCUMENTS

EXAMINE R INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
	5101313	3/31/1992	Tighe et al.	361	10	
	6400203	6/4/2002	Rezzi et al.	327	309	
	US2003/0169 025	9/11/2003	Finney	323	276	

## FOREIGN PATENT DOCUMENTS

DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION	
WO02/67279A	8/29/2002	WIPO	H01H	3/26	YES	NO

## OTHER DOCUMENTS (Including Author, Title, Date Pertinent Pages, Etc.)

	Gediga S. et al., "High Power IGBT Converters with New Gate Drive and Protection Circuit", EPE '95: 6 <sup>th</sup> . European Conference on Power Electronics and Applications, Brussels, EPE Association, Vol. 1 Conf. 6, 19 September 1995, pages 1066-1070, XP000537497

EXAMINER

DATE  
CONSIDERED

EXAMINER: Initial citation considered. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.